## **FEATURES:**

- 0.5 MICRON CMOS Technology
- Typical tsk(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- $Vcc = 2.5V \pm 0.2V$
- CMOS power levels (0.4 w typ. static)
- · Rail-to-Rail output swing for increased noise margin
- · Available in TSSOP package

## **DRIVE FEATURES:**

- · Balanced Output Drivers: ±12mA
- · Low switching noise

## **DESCRIPTION:**

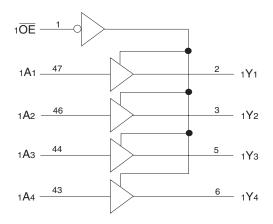
This 16-bit buffer/driver is built using advanced dual metal CMOS technology. The ALVC162244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable  $(\overline{OE})$  inputs.

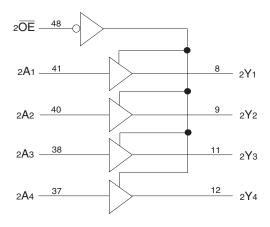
The ALVC162244 has series resistors in the device output structure which will significantly reduce line noise when used with light loads. This driver has been designed to drive  $\pm 12$ mA at the designated threshold levels.

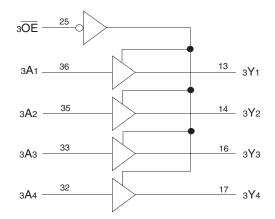
## **APPLICATIONS:**

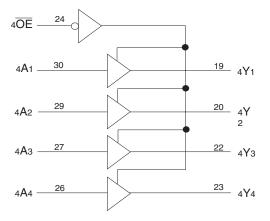
- · 3.3V high speed systems
- · 3.3V and lower voltage computing systems

## **FUNCTIONAL BLOCK DIAGRAM**







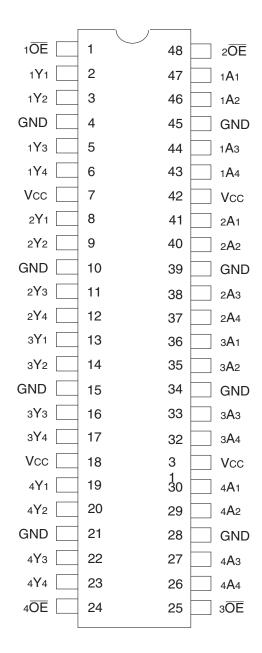


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INDUSTRIAL TEMPERATURE RANGE

**JUNE 2009** 

## **PIN CONFIGURATION**



TSSOP TOP VIEW

## **ABSOLUTE MAXIMUM RATINGS**(1)

Symbol	Description	Max	Unit
VTERM <sup>(2)</sup>	Terminal Voltage with Respect to GND	-0.5 to +4.6	V
VTERM <sup>(3)</sup>	Terminal Voltage with Respect to GND	-0.5 to Vcc+0.5	V
Tstg	Storage Temperature	-65 to +150	°C
Іоит	DC Output Current	-50 to +50	mA
lıĸ	Continuous Clamp Current, VI < 0 or VI > VCC	±50	mA
Іок	Continuous Clamp Current, Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

#### NOTES:

- 1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc.

## **CAPACITANCE** (TA = +25°C, F = 1.0MHz)

Symbol	Parameter <sup>(1)</sup>	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	5	7	pF
Соит	Output Capacitance	Vout = 0V	7	9	pF
Соит	I/O Port Capacitance	VIN = 0V	7	9	pF

#### NOTE:

1. As applicable to the device type.

## **PIN DESCRIPTION**

Pin Names	Description			
xŌĒ	3-State Output Enable Inputs (Active LOW)			
хАх	Data Inputs			
хҮх	3-State Outputs			

## FUNCTION TABLE (EACH 4-BIT BUFFER)(1)

Inp	Outputs	
х <del>ОЕ</del>	хАх	хҮх
L	Н	Н
L	L	L
Н	Х	Z

#### NOTE:

- 1. H = HIGH Voltage Level
  - X = Don't Care
  - L = LOW Voltage Level
  - Z = High-Impedance

## DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition:  $TA = -40^{\circ}C$  to  $+85^{\circ}C$ 

Symbol	Parameter	Test Con	ditions	Min.	Typ. <sup>(1)</sup>	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Iн	Input HIGH Current	VCC = 3.6V	VI = VCC	_	_	±5	μA
lıL	Input LOW Current	Vcc = 3.6V	VI = GND	_	_	±5	μA
Іоzн	High Impedance Output Current	Vcc = 3.6V	Vo = Vcc	_	_	±10	μA
lozl	(3-State Output pins)		Vo = GND	-	_	±10	
Vik	Clamp Diode Voltage	VCC = 2.3V, IIN = -18mA		_	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V			100	_	mV
ICCL ICCH ICCZ	Quiescent Power Supply Current	Vcc = 3.6V Vin = GND or Vcc		_	0.1	40	μА
∆lcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other in	puts at Vcc or GND	_	_	750	μA

#### NOTE:

## **OUTPUT DRIVE CHARACTERISTICS**

Symbol	Parameter	Test Conditions <sup>(1)</sup>		Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	IOH = -4mA	1.9	_	
			IOH = -6mA	1.7	_	
		Vcc = 2.7V	IOH = -4mA	2.2	_	
			IOH = -8mA	2	_	
		Vcc = 3V	IOH = -6mA	2.4	_	
			IOH = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	IoL = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3V	IoL = 6mA	_	0.55	
			IOL = 12mA	_	0.8	

## NOTE:

<sup>1.</sup> Typical values are at Vcc = 3.3V, +25°C ambient.

<sup>1.</sup> VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.

# **OPERATING CHARACTERISTICS, TA = 25°C**

			Vcc = 2.5V ± 0.2V		
Symbol	Parameter	Test Conditions	Typical	Typical	Unit
CPD	Power Dissipation Capacitance Outputs enabled	CL = 0pF, f = 10Mhz	16	19	pF
CPD	Power Dissipation Capacitance Outputs disabled		4	5	

## **SWITCHING CHARACTERISTICS**(1)

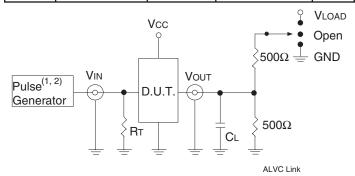
		Vcc = 2.5	5V ± 0.2V	Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Unit
tplH	Propagation Delay	1	4.9	_	4.7	1	4.2	ns
tPHL	xAx to xYx							
tpzh	Output Enable Time	1	6.8	_	6.7	1	5.6	ns
tpzL	xOE to xYx							
tphz	Output Disable Time	1	6.3	_	5.7	1	5.5	ns
tPLZ	xOE to xYx							
tsk(o)	Output Skew <sup>(2)</sup>	_	_	_	_	_	500	ps

## NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS. TA =  $-40^{\circ}$ C to  $+85^{\circ}$ C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

# TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	Vcc <sup>(1)</sup> =2.7V	Vcc <sup>(2)</sup> =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
ViH	2.7	2.7	Vcc	V
VT	1.5	1.5	Vcc / 2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



Test Circuit for All Outputs

#### **DEFINITIONS:**

CL = Load capacitance: includes jig and probe capacitance.

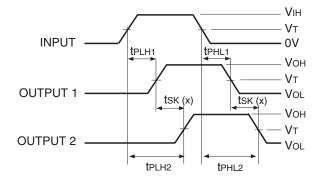
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

#### NOTES:

- 1. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tF  $\leq$  2.5ns; tR  $\leq$  2.5ns.
- 2. Pulse Generator for All Pulses: Rate  $\leq$  1.0MHz; tr  $\leq$  2ns; tr  $\leq$  2ns.

## **SWITCH POSITION**

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open

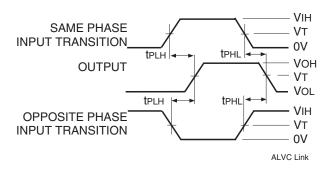


tsk(x) = |tPLH2 - tPLH1| or tpHL2 - tpHL1

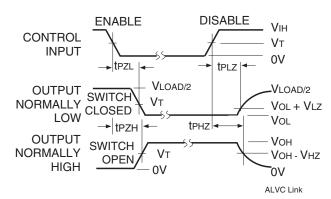
Output Skew - tsk(x)

#### NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



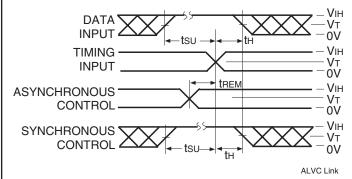
## Propagation Delay



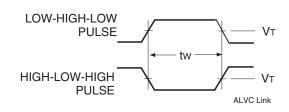
## Enable and Disable Times

#### NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

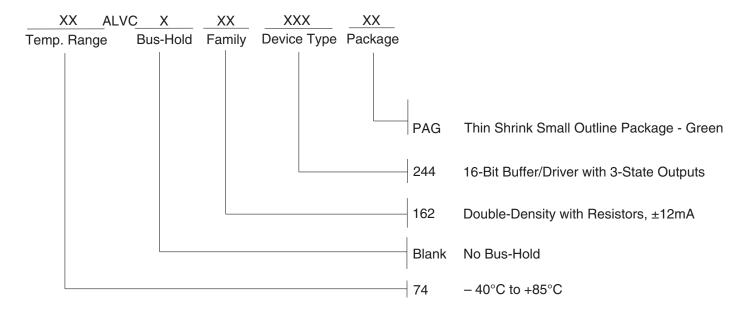


Set-up, Hold, and Release Times



Pulse Width

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